TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC4066AP, TC74HC4066AF, TC74HC4066AFT

Quad Bilateral Switch

The TC74HC4066A is a high speed CMOS QUAD BILATERAL SWITCH fabricated with silicon gate C²MOS technology.

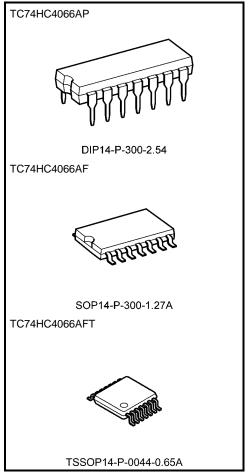
It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

Control input (C) is provided to control the switch. The switch turns ON while the C input is high, and the switch turns OFF while low.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

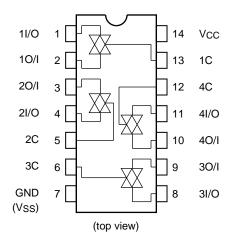
Low power dissipation: ICC = 1.0 μ A (max) at Ta = 25°C High noise immunity: VNIH = VNIL = 28% VCC (min) Low ON resistance: RON = 50 Ω (typ.) at VCC = 9 V High degree of linearity: THD = 0.05% (typ.) at VCC = 4.5 V Pin and function compatible with TC4066B series



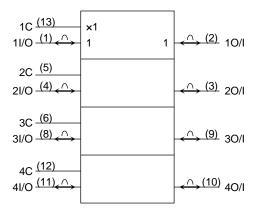
Weight

DIP14-P-300-2.54 : 0.96 g (typ.) SOP14-P-300-1.27A : 0.18 g (typ.) TSSOP14-P-0044-0.65A : 0.06 g (typ.)

Pin Assignment



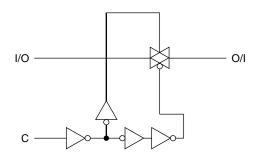
IEC Logic Symbol



Truth Table

Control	Switch Function
Н	On
L	Off

System diagram (Per Circuit)





Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 13	V
Control input voltage	VIN	-0.5 to V _{CC} + 0.5	V
Switch I/O voltage	V _{I/O}	-0.5 to V _{CC} + 0.5	V
Control input diode current	lıĸ	±20	mA
I/O diode current	II/OK	±20	mA
Switch through Current	lΤ	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	500 (DIP) (Note 1)/180 (SOP/TSSOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	oltage V _{CC} 2 to 12		V
Control input voltage	VIN	0 to VCC	V
Switch I/O voltage	VI/O	0 to VCC	V
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	t _r , tf	0 to 1000 (Vcc = 2.0 V)	
		0 to 500 (Vcc = 4.5 V)	no
		0 to 400 (Vcc = 6.0 V)	ns
		0 to 250 (Vcc = 10.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused control inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C		Unit		
- Symbol		Tool Condition	Vcc (V)	Min	Тур.	Max	Min	Max	Onic	
			2.0	1.50	_	_	1.50	_		
High-level control	V		4.5	3.15	_	_	3.15	_		
input voltage	VIHC	_	9.0	6.30	_	_	6.30	_	V	
			12.0	8.40	_	_	8.40	_		
			2.0	_	_	0.50	_	0.50		
Low-level control	VILC		4.5	_	_	1.35	_	1.35	V	
input voltage	VILC	_	9.0	_	_	2.70	_	2.70	V	
			12.0	1	_	3.60	-	3.60		
		V _{IN} = V _{IHC}	4.5	_	96	170	_	200		
		$V_{I/O} = V_{CC}$ to GND	9.0	_	55	85	_	100		
		I _{I/O} ≤ 1 mA	12.0	1	45	80	-	90		
ON resistance	Ron	$V_{IN} = V_{IHC}$ $V_{I/O} = V_{CC}$ or GND $I_{I/O} \le 1$ mA	2.0	_	160	_	_	_	Ω	
			4.5	_	70	100	_	130		
			9.0	_	50	75	_	95		
			12.0	-	45	70	-	90		
Difference of ON		V _{IN} = V _{IHC}	4.5	_	10	_	_	_		
resistance between	ΔR_{ON}	$V_{I/O} = V_{CC}$ to GND	$V_{I/O} = V_{CC}$ to GND 9.0 — 5 —		_	_	Ω			
switches		I _{I/O} ≤ 1 mA	12.0	-	5	_	-	_		
Input/output leakage		$V_{OS} = V_{CC}$ or GND								
current	IOFF	$V_{IS} = GND \text{ or } V_{CC}$	12.0	_	_	±100	_	±1000	nA	
(switch off)		VIN = VILC								
Switch input leakage current	lı z	V _{OS} =V _{CC} or GND	12.0			±100		±1000	nA	
(switch on, output open)	lız	VIN = VIHC	12.0	_	_	±100	_	±1000	ПА	
Control input current	I _{IN}	V _{IN} = V _{CC} or GND	12.0	_	_	±100	_	±1000	nA	
			6.0	_	_	1.0	_	10.0		
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND	9.0	_	_	4.0	_	40.0	μΑ	
Current			12.0	_	_	8.0	_	80.0		



AC Characteristics (CL = 50 pF, input: tr = tf = 6 ns)

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = -40 to 85°C		Unit	
		VCC (V)	Min	Тур.	Max	Min	Max	010	
			2.0	_	10	50	_	65	ns
Phase difference between input and	(D) O		4.5	_	4	10	_	13	
output	ФІ-О	_	9.0	_	3	8	_	10	
			12.0	_	3	7	_	9	
			2.0	_	18	100	_	125	
Output anable time	tpZL	$R_L = 1 k\Omega$	4.5	_	8	20	_	25	20
Output enable time	t _p zH	C _L = 50 pF	9.0	_	6	12	_	22	ns
			12.0	_	6	12	_	18	
			2.0	_	20	115	_	145	ns
Outrot disable times	tpLZ	$R_L = 1 k\Omega$	4.5	_	10	23	_	29	
Output disable time	t _{pHZ}	C _L = 50 pF	9.0	_	8	20	_	25	
			12.0	_	8	18	_	22	
		$R_L = 1 \text{ k}\Omega$ $C_L = 50 \text{ pF}$	2.0	_	30	_	_	_	MHz
Maximum control			4.5	_	30	_	_	_	
input frequency		V _{OUT} = 1/2 V _{CC}	9.0	_	30	_	_	_	IVITZ
		VOUT = 1/2 VCC	12.0	_	30	_	_	_	
Control input capacitance	C _{IN}	_		-	5	10	_	10	pF
Switch terminal capacitance	C _{I/O}	_		_	6	_	_	_	pF
Feed through capacitance	C _{IOS}	_		_	0.5	_	_	_	pF
Power dissipation capacitance	C _{PD}		(Note 1)	_	15	_	_	_	pF

Note 1: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC / 4 (per channel)



Analog Switch Characteristics (Note) (GND = 0 V, Ta = 25°C)

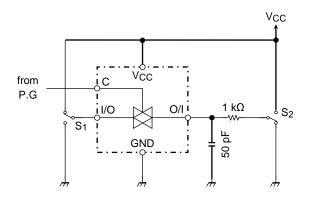
Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Sine wave distortion (T.H.D)		$f_{IN} = 1 \text{ kHz}, V_{IN} = 4 \text{ V}_{p-p}, @V_{CC} = 4.5 \text{ V}$ $R_L = 10 \text{ k}\Omega, V_{IN} = 8 \text{ V}_{p-p}, @V_{CC} = 9.0 \text{ V}$ $C_L = 50 \text{ pF}$	4.5 9.0	0.05 0.04	%
Frequency response (switch on)	f _{max}	Adjust f_{IN} voltage to obtain 0dBm at V_{OS} Increase f_{IN} frequency until dB meter reads -3dB $R_L = 50 \ \Omega, \ C_L = 10 \ pF$ $f_{IN} = 1 \ MHz, \ sine \ wave$	4.5 9.0	200 200	MHz
Feedthrough attenuation (switch off)		V_{IN} is centered at $V_{CC}/2$ Adjust input for 0dBm $R_L = 600 \ \Omega, \ C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$, sine wave	4.5 9.0	-60 -60	dB
Crosstalk (control input to signal output)		$R_L = 600 \Omega$, $C_L = 50 pF$ $f_{IN} = 1 MHz$, square wave $(t_r = t_f = 6 ns)$	4.5 9.0	60 100	mV
Crosstalk (between any switches)		Adjust V_{IN} to obtain 0dBm at input $R_L = 600 \ \Omega, \ C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$, sine wave	4.5 9.0	-60 -60	dB

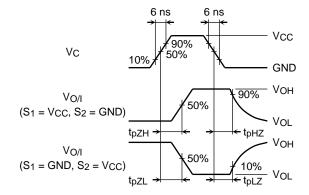
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Note: These characteristics are determined by design of devices.

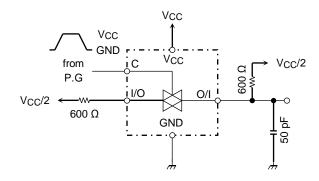
Switching Characteristics Test Circuits

1. tpLZ, tpHZ, tpZL, tpZH

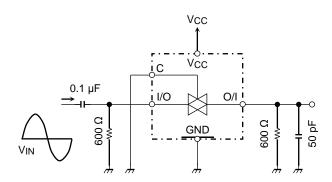




2. Cross Talk (control input-switch output) fin = 1 MHz duty = 50% tr = tf = 6 ns

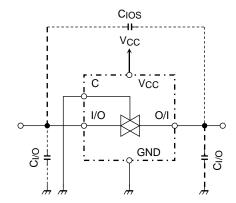


3. Feedthrough Attenuation

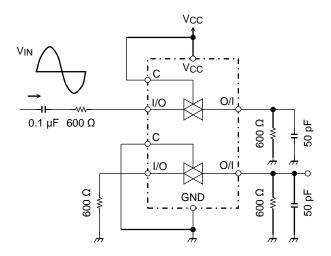




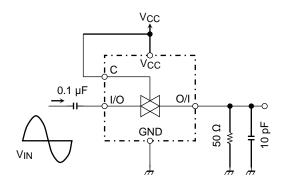
4. Cios, Ci/o



5. Crosstalk (between any two switches)



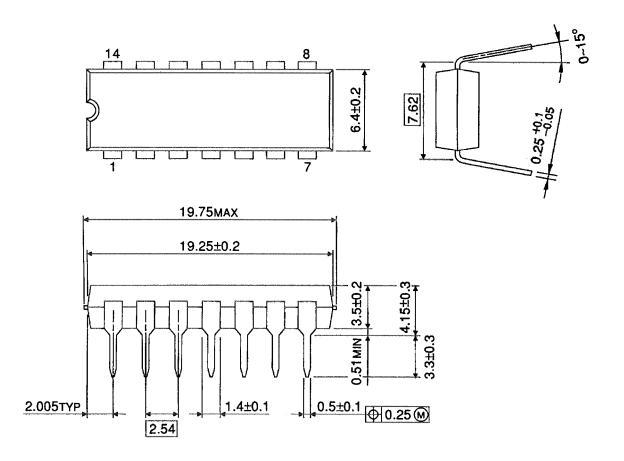
6. Frequency Response (switch on)



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Package Dimensions

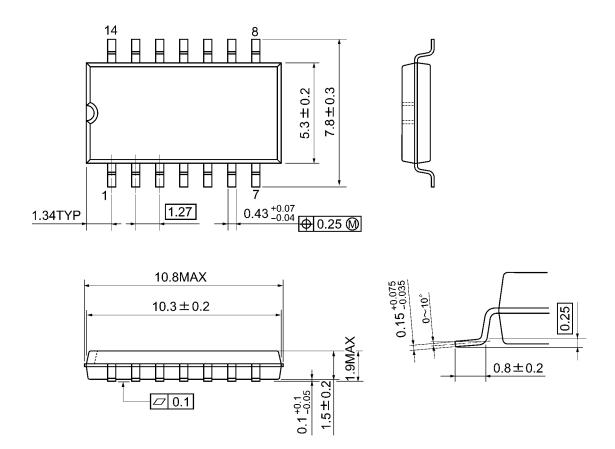
DIP14-P-300-2.54 Unit: mm



Weight: 0.96 g (typ.)

Package Dimensions

SOP14-P-300-1.27A Unit: mm



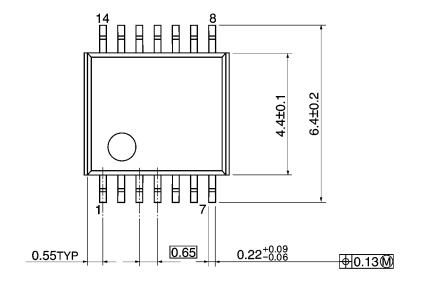
Weight: 0.18 g (typ.)

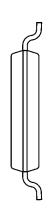


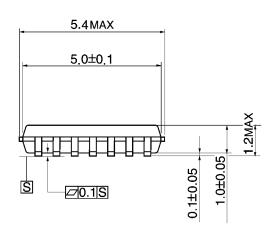
Package Dimensions

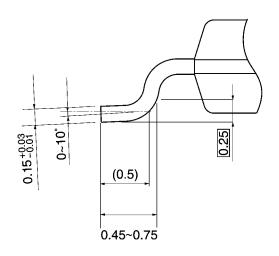
TSSOP14-P-0044-0.65A

Unit: mm









Weight: 0.06 g (typ.)

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